NSN 5961-01-181-7424

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-181-7424

Inclosure Material:

Plastic

Overall Length:

0.285 inches

Overall Diameter:

0.205 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-92

Mounting Method:

Unthreaded hole

Features Provided:

W/heat sink

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

40.0 collector to emitter voltage/static/base open and 50.0 collector to base voltage, dc and 5.0 emitter to base voltage, dc

Current Rating Per Characteristic:

2.00 amperes source cutoff current

Power Rating Per Characteristic:

1.2 watts small-signal input power, common-collector absolute

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

Special Features:

Junction pattern arrangement: pnp

Terminal Type And Quantity:

3 uninsulated wire lead and 1 unthreaded hole

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0